Size{sensitive m elting characteristics of gallium clusters: C om parison of Experiment and T heory for Ga_{17}^+ and Ga_{20}^+

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Experiments and simulations have been performed to examine the nite-tem perature behavior of Ga_{17}^+ and Ga_{20}^+ clusters. Speci cheats and average collision cross sections have been measured as a function of tem perature, and the results compared to simulations performed using rst principles D ensity {Functional M olecular{D ynamics. The experimental results show that while Ga_{17}^+ apparently undergoes a solid { liquid transition without a signi cant peak in the speci c {heat, Ga_{20}^+ melts with a relatively sharp peak. Our analysis of the computational results indicate a strong correlation between the ground {state geometry and the nite {tem perature behavior of the cluster. If the ground {state geometry is symmetric and \ordered" the cluster is found to have a distinct peak in the speci c {heat. How ever, if the ground {state geometry is am orphous or \disordered" the cluster melts without a peak in the speci c {heat.

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I. IN TRODUCTION

It is now well established that the melting points of particles with thousands of atom s decreases sm oothly with decreasing particle size, due to the increase in the surface to volume ratio.^{1,2} However, unlike particles with thousands of atom s or the bulk material, probing the

nite (tem perature properties of sm all clusters (with <500 atom s) is non { trivial and rem ains a challenging task . Experim ental studies of the melting transitions of clusters in small size regime have only recently become possible.^{3,4,5,6,7,8,9,10,11} Several interesting phenom ena have been observed, including melting temperatures that rise above the bulk value^{7,8} and strong size{dependent variations in the melting temperatures.^{9,10}. These experimental ndings have motivated many theoretical investigations on the nite {tem perature behavior of clusters.^{12,13,14,15,16,17,18} Simulations based on rst principles have been particularly successful in quantitatively explaining the factors behind the size { dependent variations in the melting behavior of clusters.¹⁷ Thus, a con uence of recent advances in experim entalm ethods and theoretical studies using st principles methods have set the stage for a m a jor increase in our understanding of phase transitions in these small systems.

C om ing to the present work on gallium clusters, it is by now well known that gallium clusters not only melt at substantially higher temperatures than the bulk $(T_{m \ [bulk]} = 303 \text{ K})$,⁸ but they also exhibit wide variations in the temperature dependences of their speci c{heats, with some clusters showing strong peaks (due to the latent heat), while others (apparent "non-melters") show – ing no peak.⁹. These features show a strong dependence on cluster size, where the addition of a single atom can change a cluster with no peak in the speci c{heat into a \m agic m elter" with a very distinct peak. This behavior has been observed for gallium clusters, Ga_n , with $n = 30\{55$.

In the present work, we probe the melting behavior of small gallium cluster ions where we show that the \non-melting" and \melting" features in the speci c{ heats are observed in clusters as small as Ga_{17}^+ and Ga_{20}^+ , respectively. Prior experimental results for Ga_{17}^+ over a lim ited tem perature range showed no evidence for a melting transition.⁸ The experimental results in this case were speci c{heat measurements performed using multi{collision induced dissociation, where a peak in the speci c{heat due to the latent heat was the signature of m elting. On the other hand, recent simulations for Ga_{17} show a broad peak in the speci c{heat centered around 600 K. The previous speci c{heat m easurem ents for G a, extended only up to 700 K, so one possible explanation for this apparent discrepancy is that the melting transition occurred at a slightly higher tem perature than exam ined in the experim ents. Here, we report speci c{heat m easurem ents for G a⁺₁₇ over a m ore extended tem perature range, along with speci c{heat measurements for Ga_{20}^+ . W hile no peak is observed in the heat{capacities for Ga_{17}^+ , a peak is observed for Ga_{20}^+ .

To further probe the melting transitions in these clusters, ion mobility measurements were performed for Ga_{17}^+ and Ga_{20}^+ as a function of temperature. The ion mobility measurements provide average collision cross sections which can reveal information about the shape and volume changes that occur on melting. For example, a cluster with a non{spherical geometry might be expected to adopt a spherical shape (a liquid droplet) on melting. If there is not a signi cant shape change, there may still be a volume change on melting. Most bulk materials expand when they melt (the liquid is less dense than the

solid). Even in the absence of a signi cant shape or volum e change, the cross sections m ight show an in ection at the melting transition due to the therm alcoe cient of expansion of the liquid cluster being larger than for the solid (in the macroscopic regim e most liquids have larger coe cients of expansion than the corresponding solids). An in ection is observed in the cross sections for both G a_{17}^+ and G a_{20}^+ . Thus, the ion mobility measurem ents suggest that G a_{17}^+ as well as G a_{20}^+ are in a liquid like state above 800 K.

To explore the reasons behind the behavior outlined above (i.e., to determ ine why Ga_{17}^+ apparently melts without a peak in its speci c{heat, while a peak is observed for Ga_{20}^+), we have carried out st principles D ensity {Functional (DF) M olecular{D ynam ics (MD) calculations on both clusters. The ground{state structure and the bonding within the clusters is analyzed. The ionic speci c{heat is computed using multiple histogram method.^{19,20} The calculated speci c{heats for Ga_{17}^+ show three broad low intensity maxima that extend from 300 to 1400 K. This resembles the experiment results where the measured speci c{heats are relatively featureless. In contrast, the calculated speci c{heats for Ga_{20}^+ show a clear peak around 750 K. This is in excellent agreem ent with the peak obtained from experim entalmeasurements (which occurs at around 700 K).Finally, our theoretical results show that the features in the speci c{heat curves are in uenced by the ground{state geometry, the bonding of the atom s within the ground { state structure, and the isom erdistribution that becom es accessible as the tem perature is raised.

In Sec. II, we present the experim ental m ethods and the computational details. In Sec. III we discuss the experim ental and theoretical results on both clusters. We conclude our results in Sec. IV.

II. METHODOLOGY

Speci c-heats were measured using the recently developed multi(collision induced dissociation approach. The cluster ions are generated by laser vaporization of a liquid gallium target in a continuous ow of helium bu er gas. A fter exiting the laser vaporization region of the source the clusters travel through a 10 cm long tem perature variable extension where their temperature is set. Cluster ions that exit the extension are focused into a quadrupole m ass spectrom eter where a particular cluster size is selected. The size selected clusters are then focused into a collision cell containing 1 Torr of helium . A s the clusters enter the collision cell they undergo num erous collisions with the helium, each one converting a small fraction of the ions translational energy into internal energy. If the initial kinetic energy is high enough som e of the cluster ions m ay be heated to the point where they dissociate. The dissociated and undissociated cluster ions are swept across the collision cellby a small electric eld and som e of them exit through a sm all aperture. The ions that exit

are analyzed in a second quadrupole mass spectrom eter and then detected by an o {axis collision dynode and dualm icrochannel plates. The fraction of the ions that dissociate is determ ined from the mass spectrum . M easurem ents are perform ed as a function of the ions initial kinetic energy, and the initial kinetic energy required for 50% dissociation (IKE 50% D) is determined from a linear regression. IKE 50% D is measured as a function of the tem perature of the tem perature (variable extension on the source. IKE 50% D decreases as the tem perature is raised because hotter clusters have m ore internal energy, and hence less energy needs to be added in order to cause dissociation. At the melting transition a sharp decrease in IKE 50% D is expected due to the latent heat. The derivative of IK E 50% D with respect to tem perature is approximately proportional to the specie c{heat. The proportionality constant is the fraction of the clusters initial kinetic energy that is converted into internal energy, which is estimated from an impulsive collision model. A drop in the IKE 50% D values due to the latent heat of a melting transition leads to a peak in the speci c{heat.

Ion m obility m easurem ents can provide inform ation on the shape and volum e changes that occur when clusters melt. For the ion mobility m easurem ents, the collision cell is replaced by a 7.6 cm long drift tube. 50 spulses of cluster ions are in jected into the drift tube and the drift tim e distribution is obtained by recording the ions arrival tim es at the detector w ith a multichannel scalar. A verage collision cross sections are obtained from the drift tim e distributions using standard m ethods.²¹

All the simulations are performed using Born { Oppenheimermolecular{dynamicsbasedonKohn{Sham formulation of Density (Functional Theory (DFT).²² W e have used Vanderbilts' ultrasoft pseudopotentials²³ within the GGA approximation, as implemented in the vasp package²⁴ for both clusters. For all calculations, we use only $4s^2$ and $4p^1$ (electrons as valence, taking the $3d\{electrons^{25} as a part of the ionic core. An energy$ cuto of about 10 Ry is used for the plane {wave expansion of the wavefunction, with a convergence in the total energy of the order of 0.0001 eV. Cubic supercells of lengths 20 and 25 A are used for Ga_{17}^+ and Ga_{20}^+ , respectively. For examining the nite {tem perature behavior, the ionic phase space of the clusters is sampled by isokinetic M D where kinetic energy is held constant via a velocity scaling m ethod. For both the clusters, we split the total tem perature range from 100{1400 K into 15 di erent tem peratures. W e m aintain the cluster at each tem perature for a period of at least 90 ps, leading to total simulation times of the order of 1 ns. The resulting trajectory data were used to compute standard therm odynam ic indicators as well as the ionic speci c{heat, via a multihistogram technique. Details can be found in Ref. 20,26.

III. RESULTS AND DISCUSSION

Speci c{heats m easured for Ga_{17}^+ and Ga_{20}^+ as a func tion oftem perature are shown in the lower half of Fig. 1 The points are the experim ental values, while the dashed line is the prediction of a modi ed Debye model. In th case of Ga_{17}^+ , the speci c{heats shown in Fig. 1 appear to gradually increase up to around 900 K. The sharp de crease in the speci c{heats above 900 K is an artifac due to evaporative cooling, the spontaneous unim olec ular dissociation of the cluster ions as they travel be tween the source extension and the collision cell. For Ga_{20}^+ , the speci c{heats show a broad maximum, around 400 K wide, centered at around 725 K. The peak for Ga_{20}^+ is signi cantly broader than observed for larger clusters (Like Ga_{39}^+ and Ga_{40}^+) where the peak was attributed to a melting transition. However, it is well known that the melting transition, and the corresponding peak in the speci c{heats, becom es broader with decreasing cluster size. Thus, even though the peak in the speci c-heats for Ga_{20}^+ is around 400 K wide, it is appropriate to assign it to a nite { size analog of a bulk melting transition. The center of the peak is at around 725 K, this is well above the bulk melting point (303 K). This continues a trend reported for larger cluster sizes ($n = 30{55}$) where the melting tem peratures are also signi cantly above the bulk value. The un lled red circles in Fig. 1 show the average collision cross sections determ ined for Ga_{17}^+ and Ga_{20}^+ as a function of the tem perature. The cross sections are expected to system atically decrease with increasing tem perature because the long range attractive interactions between the cluster ion and the bu er gas atom s becom es less in portant, and the collisions becom e harder as the tem perature is raised. The thick dashed red line in the gures show the expected exponential decrease in the cross sections with increasing tem perature. There is an in ection in the cross sections for Ga_{20}^+ that appears to slightly precede the peak in the speci c{heat for this cluster. The in ection in consistent with a melting transition where the liquid cluster has a larger coe cient of therm al expansion than the solid. There is also an in ection in the cross sections for Ga_{17}^+ . This suggests that a solid { liquid transition also occurs for Ga_{17}^+ , but without a signi cant peak in the speci c{heat.

To understand the reason behind the di erent behavior observed for G a_{17}^+ and G a_{20}^+ , we have carried out a detailed analysis of structure and bonding in both clusters. A s will be become apparent from the following discussion, that the ground{state geometry and the nature of bonding plays a crucial role in determining the nite{ tem perature behavior of the cluster. We begin with a discussion of the ground{state geometries of cationic G a_{17} and G a_{20} clusters. We have obtained more than 50 distinct equilibrium geometries by quenching more than 200 structures, selected from a few high tem perature M D runs, for both sizes. In Fig. 2, we show the lowest energy structure along with some low lying excited state geometries of both clusters. The lowest energy geometry

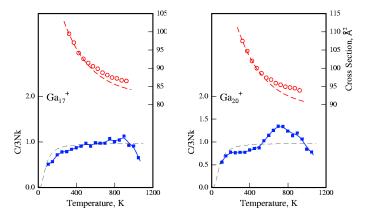


FIG.1: Speci c{heats and average collision cross sections measured for size{selected Ga_{17}^+ and Ga_{20}^+ clusters as a function of temperature. The solid blue points show the speci c{heats which are normalized to 3N k_B (the classical value), where k_B is the Boltzm ann constant and N = (3n 6 + 3=2)=3 (n = num ber of atom s in the cluster, and 3n 6 and 3/2 are due to the vibrational and rotational contributions, respectively).

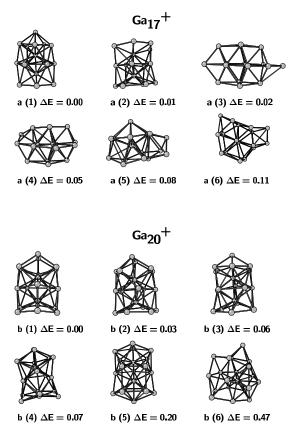
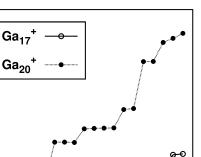


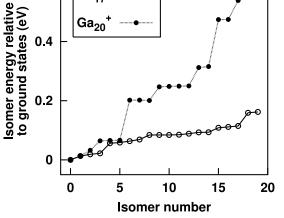
FIG.2: The ground {state and some representative low { lying and excited {state geom etries of Ga_{17}^+ and Ga_{20}^+ clusters. Fig (1) corresponds to the ground {state geom etry. The energy di erence E is given in eV with respect to the ground {state.

of the Ga_{17}^+ cluster (see Fig. 2{a(1)) is similar to that of G a_{17} reported in our earlier work.¹² It has a distorted decahedral structure, which suggests the possibility of further cluster growth to a 19{atom double decahedron. In contrast, the ground { state geom etry of G a_{20}^+ , show n in Fig. 2{b(1), is more symmetric. It can be described as a double decahedral structure of 19 atom s, with the bottom capped atom merging into the pentagonal plane to form a hexagonal ring. In addition, an atom from the top pentagon and the upper capped atom rearrange to accomm odate the 20th atom, leading to a dom e{shaped hexagonal ring.

W e now analyze the structural properties in detail to get an insight into the features that in uence the melting characteristics. An analysis of the bond { length distribution shows that there are 12 bonds, for each cluster, having distances less than 2.55 A \cdot^{27} Interestingly, for G a_{17}^+ , these short bonds are spread all over the cluster, whereas for $\operatorname{Ga_{20}}^+$, they form the upper and the lower hexagonal rings. The distribution of coordination num bers28 indicate that for ${{\sf G}\,{\sf a_{20}}^+}$, alm ost all the atom s in the rings (about 16), have a coordination num ber of 4. The G a_{17}^+ cluster, how ever, does not have such a uniform distribution of coordination num bers. Thus, the ground { state geom etry of G a_{17}^+ m ight be considered to be \disordered", while that of Ga_{20}^+ exhibits a more{ordered structure.

Striking di erences are also observed in the low energy isom ers and their distribution on the potential (energy surface. As mentioned above, we have obtained more than 50 distinct isomers spanning an energy range of about 1.0 eV above the ground { states for each cluster. In Fig. 3, we plot the energies of these isom ers relative to the ground{state, arranged in an ascending order. The isom ers for the G a_{17}^+ cluster appear to exhibit an alm ost continuous energy distribution. W hile a few of these isom ers are severe distortions of the ground { state geom etry, the rest do not show any resemblance (see Fig. 2a). It appears that for the Ga_{17}^+ isom ers in this low energy regime, small rearrangements of the atoms, costing just a sm allam ount of energy, lead to several close-lying isomers, so that the isomer distribution is almost continuous. In contrast, the isomers of Ga_{20}^+ cluster are distributed in three groups, separated by an energy gap of about 0.2 eV (Fig. 3). The rst group of isom ers have slightly di erent orientations of atom s in the hexagonal rings and are nearly degenerate with the ground { state. The second group consists of structures having only the lower hexagonal ring while the third group has no rings. This indicates that the hexagonal units of Ga_{20}^+ cluster are stable and di cult to break. The stability of the ring { pattern of $G a_{20}^+$ and the isomer distribution for both clusters should have a substantial e ect on the melting characteristics. Indeed, as we shall see further below, these features play a crucial role in the nite{ tem perature characteristics. It should be mentioned that although these observations are based on rather limited search, we believe that the general features described here are essentially correct.





0.6

0.4

0.2

FIG.3: The energies of the isomeric structures of Ga_{17}^+ and Ga_{20}^+ with respect to their ground { states.

TABLE I: The number of basins with more than one atom at di erent values of the electron localization function for the ground{state structures of Ga_{17}^+ and Ga_{20}^+ clusters. The num bers in parenthesis represent the num ber of atom s in each basin.

ELF value	G a ₁₇ +	$\operatorname{Ga_{20}}^+$
0.85	0	1 (2)
0.77	1 (2)	2 (5,7)
0.75	3 (2,2,2)	2 (5,7)
0.73	2 (3,4)	1 (14)

The most important di erence between the two clusters is the nature of the bonding. We use the concept of an electron localization function (ELF) $_{r}^{29}$ to describe the nature of bonding. This function is norm alized to a value between zero and unity; a value of 1 represents a perfect localization of the valence charge while the value for the uniform electron gas is 1/2. The locations of maxim a of this function are called attractors, since other points in space can be connected to them by paths of maximum gradient. The set of all such points in space that are attracted by a maximum is de ned to be the basin of that attractor. Basin form ations are usually observed as the value of the ELF is lowered from its maximum, at which there are as m any basins as the num ber of atom s in the system . Typically, the existence of an isosurface or a basin in the bonding region between two atoms at a high ELF value, say 0:70, signi es a localized bond in that region.

W e have analyzed the electron localization functions for Ga_{17}^+ and Ga_{20}^+ clusters for values 0.85. In Table I, we give the num ber of basins containing two orm ore atom s, for selected ELF values. The table clearly show s a fragm ented grow th pattern of the basins for Ga_{17}^+ , each containing very few atom s as compared to that of G a_{20}^+ . For instance, at an isovalue of 0.75, while Ga_{17}^+ has three

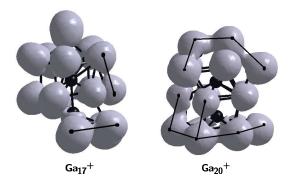


FIG.4: The isosurface for the electron localization functions for $G a_{17}^+$ and $G a_{20}^+$ at an isovalue of 0.75. The black lines correspond to merged basin structures.

basins each having 2 atom s, $G a_{20}^+$ has just two basins each containing 5 and 7 atom s that corresponds to the two hexagonal rings. The ELF contours for the isovalue of 0.75 are shown in Fig.4. The merged basins structures are shown by the black lines. It may be inferred that the bonds between atom s in the hexagonal rings of $G a_{20}^+$ are strong and covalent in nature with sin ilar strengths, while the fragmented basin grow th pattern in $G a_{17}^+$ indicates inhom ogeneity of the bond strengths.

The calculated, normalized, canonical speci c{heats are shown in Fig. 5 plotted against temperature. The plot for Ga_{17}^+ exhibits a broad feature (apparently consisting of three components) which extends from 300 K to 1400 K.For $\operatorname{Ga_{20}}^+$, the calculated speci c{heat remains nearly at up to about 600 K, it then increases sharply and peaks at about 800 K, in excellent agreem ent with the experim ental results described above. Thus, interesting size {sensitive features seen in the experim ental heat (capacities are reproduced in our simulations. This behavior can be understood from our earlier discussion of the bond { length distributions, coordination num bers, isom er{distributions, and the nature of bonding in these clusters. W hile the Ga_{17}^+ cluster shows no real evidence for ordered behavior, the Ga_{20}^+ cluster has well{ordered} ring { patterns. Thus, when $G a_{17}^+$ is heated, the bonds soften gradually, and the cluster hops through all its isom ers continuously. This is clearly dem onstrated by the ionic motion as a function of tem perature, which shows that this cluster evolves through all isomers smoothly from 300 K to 1400 K.On the other hand, the ionic motion for Ga_{20}^+ shows only m inor rearrangem ents of the atom s until 600 K, and then the cluster visits all the isom ers corresponding to the st group of isom ers described above. At about 700 K, the upper hexagonal ring breaks, while at about 800 K, the lower ring breaks. Thus, melting of Ga₂₀⁺ cluster is associated with the breaking of the well{ordered covalently bonded hexagonal units.

W e have also analyzed the melting characteristics via traditional parameters such as, the root{mean{squared bond{length{ uctuations ($_{ms}$) and the mean{squared ionic displacements (MSD). In Fig. 6, we show the $_{ms}$

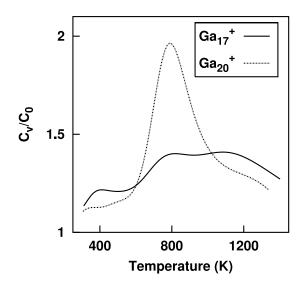


FIG. 5: Normalized canonical speci c{heat for Ga_{17}^+ (continuous{line) and Ga_{20}^+ (dashed{line). $C_0 = (3n \ 6 + 3=2)k_B$ is the zero tem perature classical lim it of the rotational plus vibrational canonical speci c{heat.

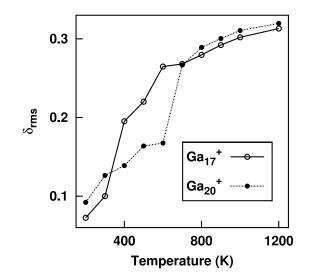


FIG.6: Root{m ean{square bond{length{ uctuations ($_{m s}$) for G a_{17}^+ (continuous{line) and G a_{20} (dashed{line).

for G a_{17}^+ and G a_{20}^+ clusters. This plot correlates well with the speci c{heat curve shown in Fig. 5. The ms for G a_{17}^+ rises gradually from 300 K, while for G a_{20}^+ , it rises sharply at about 700 K, and nally saturates to the same value for both clusters. It may be inferred from this observation that the behavior of both clusters at tem peratures say, T 800 K, are sim ilar and that both clusters can be considered to be in liquidlike states. This conclusion is further substantiated by the M SD plots (gures not shown), which saturate at 21A², at about 1200 K for both clusters. It is evident from the present study that the nature of the ground{state geometry and bonding strongly in-

uences the nite {tem perature characteristics of $G_{q_7}^+$ and Ga_{20}^+ . At high temperatures, T 800 K, both Ga_{17}^+ and Ga_{20}^+ have sim ilar root {m ean {squared bond { length { uctuations and the mean { squared ionic displacements so that both of them can be considered to be in liquidlike states. The experim ental results show that while Ga_{17}^+ apparently undergoes a solid { liquid transition without a signi cant peak in the speci c{heat, Ga_{20}^+ melts with a relatively sharp peak. The simulations show that if the cluster is \ordered" (i.e. a large fraction of the constituent atom s show sim ilar bonding, coordination num bers, and bond energies) then it is likely to show a sharp melting transition with a signi cant peak in the speci c{heat. On the other hand, if the cluster is \disordered" (i.e. the constituent atom s occur in a wide distribution of bonding environments) it will probably undergo a solid { liquid transition without a signi cant peak in the speci c{heat. In the latter case, the num ber of isom ers or conform ations sam pled by the cluster increases steadily as the tem perature is raised, instead of the abrupt increase that occurs when a cluster undergoes a sharp melting transition.

These observations have interesting consequences for the nite{tem perature behavior of sm all clusters as a function of cluster size. It is likely that as clusters grow in size their structures evolve from one well{ordered struc-

ture to another, passing on the way through som e cluster sizes that have \disordered" structures. For instance, the 13 {atom gallium cluster is predicted to have a highly symmetric decahedron structure with a bonding pattern that is similar to that found here for Ga_{20}^+ .¹² So in the present case, cluster growth from Ga_{13} (a decahedron) to (Ga_{20}^+) , a distorted double (decahedron) proceeds via a disordered Ga_{17}^+ structure. Such behavior is also observed for sodium clusters in 40 to 55 atom size range; the ground { state geometries of Na_{40} and Na_{55} are either icosahedron or close to icosahedron while that of $N\,a_{50}$ has no particular sym m etry 17,18 In such cases, we expect that the speci c{heats should change from showing a well{de ned peak to a rather broad one, and back again to well{de ned. We believe this behavior to be generic as it has not only been observed in case of gallium clusters^{8,9} but also in case of alum inum clusters¹⁰, experimentally, and for sodium clusters in the simulations m entioned above.

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fect the equilibrium geometries and the nite (temperature behavior.

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- ²⁷ A typical bond {distance of a metallic bond seen in the extended system, i.e.: {gallium, is about 2.79 A.
- ²⁸ The co{ordination number is computed by counting the number of atom lying within a sphere of radius of 2.79 A. The radius 2.79 A is chosen since this value corresponds to

the maximum bond { length of a metallic bond in the {G a bulk phase. For a description of {G a see, for instance, X.G.Gong, X.G.Gong, G.L.Chiarotti, M.Parrinello, and E.Tosatti, Phys.Rev.B 43, 14277 (1991); V.Heine, J.Phys.C 1, 222 (1968); V.Heine and D.W eaire, Solid State Phys.24, 249 (1970).

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